



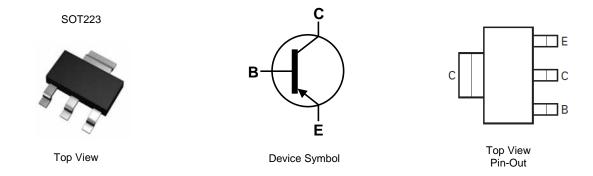
#### **60V PNP MEDIUM POWER TRANSISTOR IN SOT223**

#### Features

- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -5A High Continuous Collector Current
- I<sub>CM</sub> = -15A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(SAT)</sub> < -140mV @ -1A</li>
- $R_{CE(SAT)} = 55m\Omega$  for a Low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: FZT851
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



#### Ordering Information (Notes 4 & 5)

<b></b>				-	
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT951TA	AEC-Q101	FZT951	7	12	1000
FZT951TC	AEC-Q101	FZT951	13	12	4000
FZT951QTA	Automotive	FZT951	7	12	1000
FZT951QTC	Automotive	FZT951	13	12	4000

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

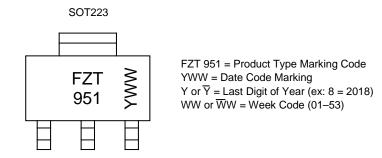
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**





#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-5	А
Peak Pulse Current	I <sub>CM</sub>	-15	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	5	3.0 24	W	
Linear Derating Factor	(Note 7)	PD	1.6 12.8	mW /°C	
The second Desciptor and the still and the Architect	(Note 6)	R <sub>ØJA</sub>	42		
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>ØJA</sub>	78	°C/W	
Thermal Resistance Junction to Lead	(Note 8)	R <sub>ƏJL</sub>	8.8		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

# ESD Ratings (Note 9)

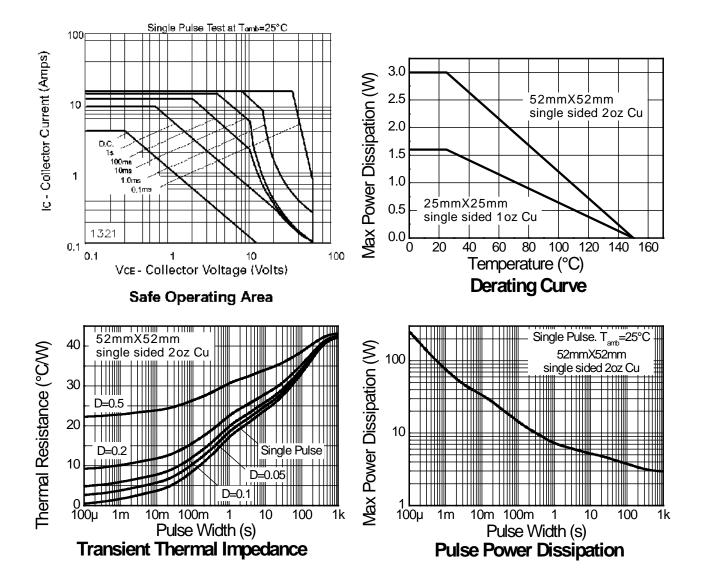
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Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	8000	V	3B
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

Same as Note 6, except the device is mounted on 25mm × 25mm 1oz copper.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





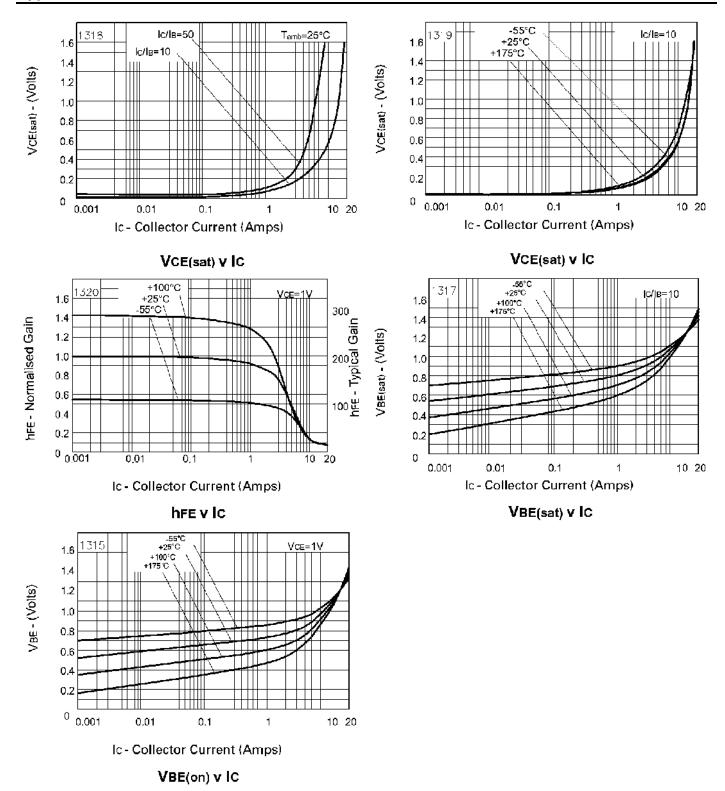
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-100	-140	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CER</sub>	-100	-140	—	V	I <sub>C</sub> = -1μA, R <sub>B</sub> ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 10)	BVCEO	-60	-90	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8	—	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>СВО</sub>	_	<-1	-50 -1	nA µA	V <sub>CB</sub> = -80V V <sub>CB</sub> = -80V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	I <sub>CER</sub>	_	<-1 —	-50	nA µA	$V_{CE} = -80V, T_A = +100 C$ $V_{CE} = -80V, R \le 1k\Omega$ $V_{CE} = -80V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>		<1	-10	nA	$V_{EB} = -6V$
DC Current Transfer Static Ratio (Note 10)	h <sub>FE</sub>	100	200			$I_{\rm C} = -10 {\rm mA}, V_{\rm CE} = -1 {\rm V}$
		100	200	300		$I_{C} = -2A, V_{CE} = -1V$
		75	90	_		$I_{\rm C} = -5A, V_{\rm CE} = -1V$
		10	25	_		I <sub>C</sub> = -10A, V <sub>CE</sub> = -1V
	Vce(sat)	_	-20	-50	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
Collector-Emitter Saturation Voltage (Note 10)		_	-85	-140		$I_{\rm C} = -1$ A, $I_{\rm B} = -100$ mA
Collector-Emilier Saturation Voltage (Note 10)		—	-155	-210		$I_{\rm C} = -2A, I_{\rm B} = -200 {\rm mA}$
		—	-370	-460		$I_{C} = -5A, I_{B} = -500mA$
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(SAT)</sub>	_	-1080	-1240	mV	$I_{C} = -5A, I_{B} = -500mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(ON)</sub>	-	-935	-1070	mV	$I_{C} = -5A, V_{CE} = -1V$
Transitional Frequency (Note 10)	f <sub>T</sub>	_	120	—	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V, f = 50MHz
Output Capacitance	C <sub>OBO</sub>		74	_	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Time	ton		82	_	20	$V_{CC} = -10V, I_C = -2A,$
Switching Time	t <sub>OFF</sub>	—	350	—	ns	$-I_{B1} = I_{B2} = -200 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



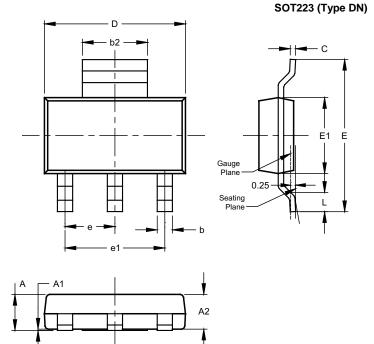
#### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# **Package Outline Dimensions**

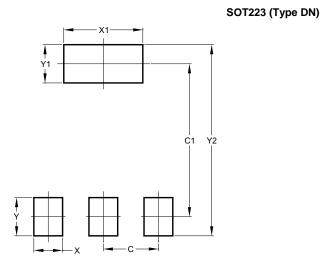
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)					
Dim	Min Max		Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1		-	4.60		
L	0.85				
All Dimensions in mm					

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



# Dimensions Value (in mm) C 2.30 C1 6.40 X 1.20 X1 3.30 Y 1.60 Y1 1.60 Y2 8.00



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